## NSN 5962-01-169-8025

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 1.060 inches and 1.100 inches
Body Width:
0.400 inches
Body Height:
Between 0.145 inches and 0.175 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Trainer, simulator, electronic warfare an/alq-t5
Features Provided:
Hermetically sealed and bipolar and 3-state output and schottky
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
20 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
45.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883  standard (includes industry or association standards, individual manufactureer standards,   etc.).
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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